NSN 5961-01-033-8019

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View Online at https://aerobasegroup.com/nsn/5961-01-033-8019 **Inclosure Material:** Metal **Overall Length:** Between 0.380 inches and 0.420 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.330 inches and 0.355 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, collector-to-base, emitter open and 65.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6145 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: